SPDT, 3 Ω R_{ON} Switch

The NLAS9031 is an advanced CMOS analog switch fabricated with silicon gate CMOS technology. It achieves very low propagation delay and $RDS_{(on)}$ resistances while maintaining CMOS low power dissipation. Analog and digital voltages that may vary across the full power–supply range (from V_{CC} to GND). This device is a drop in replacement for the NC7S9031.

The select pin has overvoltage protection that allows voltages above V_{CC} , up to 7.0 V to be present on the pin without damage or disruption of operation of the part, regardless of the operating voltage.

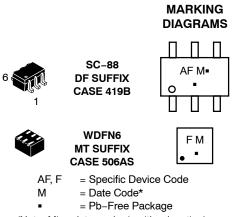
Features

- High Speed: $t_{PD} = 1.0 \text{ ns} (Typ) \text{ at } V_{CC} = 5.0 \text{ V}$
- Low Power Dissipation: $I_{CC} = 2.0 \ \mu A$ (Max) at $T_A = 25^{\circ}C$
- Standard CMOS Logic Levels
- High Bandwidth, Improved Linearity
- Switches Standard NTSC/PAL Video, Audio, SPDIF and HDTV
- May be used for Clock Switching, Data Multiplexing, etc.
- R_{ON} Typical = 3 Ω @ V_{CC} = 4.5 V
- Break Before Make Circuitry, Prevents Inadvertent Shorts
- 2 Devices can Switch Balanced Signal Pairs, e.g. LVDS > 200 Mb/s
- Latchup Performance Exceeds 300 mA
- Pin for Pin Drop in for NC7S9031
- Tiny SC88 and WDFN6 Packages
- ESD Performance:
 - Human Body Model; > 2000 V;
 - Machine Model; > 200 V
- Extended Automotive Temperature Range -55°C to +125°C (See Appendix)
- Pb-Free Packages are Available



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(Note: Microdot may be in either location) *Date Code orientation may vary depending upon manufacturing location.

FUNCTION TABLE

Select Input	Function
L	B0 Connected to A
H	B1 Connected to A

ORDERING INFORMATION

Device	Package	Shipping [†]
NLAS9031DFT2G	SC-88 (Pb-Free)	3000 Tape & Reel
NLAS9031MTR2G	WDFN6 (Pb-Free)	3000 Tape & Reel

†For information on tape and reel specifications,

including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

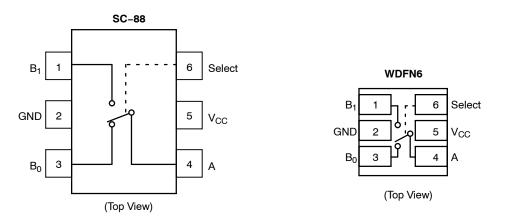


Figure 1. Pin Assignment & Logic Diagram

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Supply Voltage	V _{CC}	-0.5 to +7.0	V
DC Switch Voltage (Note 1)	V _S	–0.5 to V _{CC} + 0.5	V
DC Input Voltage (Note 1)	V _{IN}	-0.5 to + 7.0	V
DC Input Diode Current @ $V_{IN} < 0 V$	IIK	-50	mA
DC Output Current	I _{OUT}	128	mA
DC V _{CC} or Ground Current	I _{CC} /I _{GND}	+100	mA
Storage Temperature Range	T _{stg}	-65 to +150	°C
Junction Temperature Under Bias	TJ	150	°C
Junction Lead Temperature (Soldering, 10 Seconds)	TL	260	°C
Power Dissipation @ +85°C	PD	180	mW

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.

RECOMMENDED OPERATING CONDITIONS (Note 2)

Characteristic	Symbol	Min	Max	Unit
Supply Voltage Operating	V _{CC}	1.65	5.5	V
Select Input Voltage	V _{IN}	0	V _{CC}	V
Switch Input Voltage	V _{IN}	0	V _{CC}	V
Output Voltage	V _{OUT}	0	V _{CC}	V
Operating Temperature	T _A	-55	+125	°C
Input Rise and Fall Time Control Input V_{CC} = 2.3 V–3.6 V Control Input V_{CC} = 4.5 V–5.5 V	t _r , t _f	0 0	10 5.0	ns/V
Thermal Resistance	θ_{JA}	-	350	°C/W

2. Select input must be held HIGH or LOW, it must not float.

DC ELECTRICAL CHARACTERISTICS

		Vcc		T _A = +25°C		T _A = -40°		
Parameter	Test Conditions	(V)	Min	Тур	Мах	Min	Max	Unit
HIGH Level Input Voltage		1.65–1.95 2.3–5.5				0.75 V _{CC} 0.7 V _{CC}		V
LOW Level Input Voltage		1.65–1.95 2.3–5.5					0.25 V _{CC} 0.3 V _{CC}	V
Input Leakage Current	$0 \le V_{IN} \le 5.5 \text{ V}$	0–5.5		±0.05	± 0.1		±1	μA
OFF State Leakage Current	$0 \le A, B \le V_{CC}$	1.65–5.5		±0.05	±0.1		±1	μΑ
Switch On Resistance (Note 3)		4.5		3.0 5.0 7.0			7.0 12 15	Ω
	$V_{IN} = 0 V$, $I_O = 24 mA$ $V_{IN} = 3 V$, $I_O = -24 mA$	3.0		4.0 10			9.0 20	Ω
	$V_{IN} = 0 V$, $I_O = 8 mA$ $V_{IN} = 2.3 V$, $I_O = -8 mA$	2.3		5.0 13			12 30	Ω
	$V_{IN} = 0 V$, $I_O = 4 mA$ $V_{IN} = 1.65 V$, $I_O = -4 mA$	1.65		6.5 17			20 50	Ω
Quiescent Supply Current All Channels ON or OFF	V _{IN} = V _{CC} or GND I _{OUT} = 0	5.5			1.0		10	μΑ
Analog Signal Range		V _{CC}	0		V _{CC}	0	V _{CC}	V
On Resistance Over Signal Range (Note 3) (Note 7)	$I_A = -30 \text{ mA}, 0 \le V_{Bn}$ $\le V_{CC}$ $I_A = -24 \text{ mA}, 0 \le V_{Bn}$	4.5 3.0					25 50	Ω
	$\leq V_{CC}$ I _A = -8 mA, 0 $\leq V_{Bn}$	2.3					100	
	\leq V _{CC} I _A = -4 mA, 0 \leq V _{Bn} \leq V _{CC}	1.65					300	
On Resistance Match Between Channels (Note 3) (Note 4) (Note 5)	$ \begin{array}{l} I_A = -30 \text{ mA}, \text{ V}_{Bn} = 3.15 \\ I_A = -24 \text{ mA}, \text{ V}_{Bn} = 2.1 \\ I_A = -8 \text{ mA}, \text{ V}_{Bn} = 1.6 \\ I_A = -4 \text{ mA}, \text{ V}_{Bn} = 1.15 \end{array} $	4.5 3.0 2.3 1.65		0.15 0.2 0.5 0.5				Ω
On Resistance Flatness (Note 3)	$I_A = -30 \text{ mA}, 0 \le V_{Bn} \le V_{CC}$	5.0		6.0				Ω
(Note 4) (Note 6)	$I_A = -24 \text{ mA}, 0 \le V_{Bn} \le V_{CC}$	3.3 2.5		12 28				
	$I_A = -8 \text{ mA}, 0 \le V_{Bn}$ $\le V_{CC}$ $I_A = -4 \text{ mA}, 0 \le V_{Bn}$	2.5 1.8		28 125				
	HIGH Level Input Voltage Input Leakage Current OFF State Leakage Current Switch On Resistance (Note 3) Quiescent Supply Current All Channels ON or OFF Analog Signal Range On Resistance Over Signal Range (Note 3) (Note 7) On Resistance Match Between Channels (Note 3) (Note 4) (Note 5) On Resistance Flatness (Note 3)	HIGH Level Input VoltageImput VoltageLOW Level Input Voltage $0 \le V_{IN} \le 5.5 V$ OFF State Leakage Current $0 \le A, B \le V_{CC}$ Switch On Resistance (Note 3) $V_{IN} = 0 V, I_O = 30 \text{ mA}$ $V_{IN} = 2.4 V, I_O = -30 \text{ mA}$ $V_{IN} = 2.4 V, I_O = -30 \text{ mA}$ $V_{IN} = 4.5 V, I_O = -30 \text{ mA}$ $V_{IN} = 3 V, I_O = -24 \text{ mA}$ $V_{IN} = 3 V, I_O = -24 \text{ mA}$ $V_{IN} = 3 V, I_O = -8 \text{ mA}$ $V_{IN} = 0 V, I_O = 8 \text{ mA}$ $V_{IN} = 0 V, I_O = 8 \text{ mA}$ $V_{IN} = 1.65 V, I_O = -8 \text{ mA}$ Quiescent Supply Current All Channels ON or OFF $V_{IN} = V_{CC} \text{ or GND}$ $I_{OUT} = 0$ Analog Signal Range (Note 3) (Note 7) $I_A = -30 \text{ mA}, 0 \le V_{Bn}$ $\le V_{CC}$ $I_A = -30 \text{ mA}, 0 \le V_{Bn}$ $\le V_{CC}$ $I_A = -4 \text{ mA}, 0 \le V_{Bn}$ $\le V_{CC}$ On Resistance Match Between Channels (Note 3) (Note 4) (Note 5) $I_A = -30 \text{ mA}, V_{Bn} = 3.15$ $I_A = -24 \text{ mA}, 0 \le V_{Bn}$ $\le V_{CC}$ On Resistance Flatness (Note 3) (Note 4) (Note 6) $I_A = -30 \text{ mA}, 0 \le V_{Bn}$ $\le V_{CC}$ $I_A = -30 \text{ mA}, 0 \le V_{Bn}$ $\le V_{CC}$ On Resistance Match Between Channels (Note 3) (Note 4) (Note 6) $I_A = -30 \text{ mA}, 0 \le V_{Bn}$ $\le V_{CC}$ $I_A = -30 \text{ mA}, 0 \le V_{Bn}$ $\le V_{CC}$	$\begin{array}{ c c c c c } HIGH Level \\ Input Voltage & 1.65-1.95 \\ 2.3-5.5 \\ LOW Level \\ Input Voltage & 2.3-5.5 \\ Input Leakage Current & 0 \leq V_{IN} \leq 5.5 V & 0-5.5 \\ \hline OFF State Leakage \\ Current & 0 \leq A, B \leq V_{CC} & 1.65-5.5 \\ \hline OFF State Leakage \\ Current & V_{IN} = 0 V, I_O = 30 mA \\ V_{IN} = 2.4 V, I_O = -30 mA \\ V_{IN} = 4.5 V, I_O = -30 mA \\ V_{IN} = 3 V, I_O = -30 mA \\ V_{IN} = 3 V, I_O = -30 mA \\ V_{IN} = 0 V, I_O = 8 mA \\ V_{IN} = 2.3 V, I_O = -4 mA \\ V_{IN} = 0 V, I_O = 4 mA \\ V_{IN} = 1.65 V, I_O = -4 mA \\ V_{IN} = 0 V, I_O = 4 mA \\ V_{IN} = 0 V, I_O = 4 mA \\ V_{IN} = 0 V, I_O = 4 mA \\ V_{IN} = 0 V, I_O = 4 mA \\ V_{IN} = 0 V, I_O = -4 mA \\ V_{IN} = 0 V, I_O = -4 mA \\ V_{IN} = 1.65 V, I_O = -4 mA \\ V_{IN} = 0 V, I_O = -4 mA \\ V_{IN} = 0 V, I_O = -4 mA \\ V_{IN} = 0 V, I_O = -4 mA \\ V_{IN} = 0 V, I_O = -4 mA \\ V_{IN} = 0 V, I_O = -4 mA \\ V_{IN} = 0 V, I_O = -4 mA \\ V_{IN} = 0 V, I_O = -4 mA \\ V_{IN} = 0 V, I_O = -4 mA \\ V_{IN} = 0 V, I_O = 0 \\ \hline DN Resistance Match \\ I_A = -30 mA, 0 \leq V_{Bn} = 1.6 \\ I_A = -4 mA, V_{Bn} = 1.15 \\ I_A = -4 mA, 0 \leq V_{Bn} \\ \leq V_{CC} \\ I_A = -4 mA, 0 \leq V_{Bn} \\ \leq V_{CC} \\ I_A = -4 mA, 0 \leq V_{Bn} \\ \leq V_{CC} \\ I_A = -4 mA, 0 \leq V_{Bn} \\ \leq V_{CC} \\ I_A = -4 mA, 0 \leq V_{Bn} \\ \leq V_{CC} \\ I_A = -4 mA, 0 \leq V_{Bn} \\ \leq V_{CC} \\ I_A = -4 mA, 0 \leq V_{Bn} \\ \leq V_{CC} \\ I_A = -$	Parameter Test Conditions V _{CC} (V) HIGH Level Input Voltage 1.65-1.95 2.3-5.5 1.65-1.95 2.3-5.5 LOW Level Input Voltage 0 $\leq V_{IN} \leq 5.5 V$ 0-5.5 Input Leakage Current 0 $\leq V_{IN} \leq 5.5 V$ 0-5.5 OFF State Leakage Current 0 $\leq A, B \leq V_{CC}$ 1.65-1.95 Switch On Resistance (Note 3) $V_{IN} = 0 V, I_O = 30 \text{ mA}$ $V_{IN} = 4.5 V, I_O = -30 \text{ mA}$ $V_{IN} = 2.4 V, I_O = -30 \text{ mA}$ 4.5 VIN = 0 V, I_O = 4 mA $V_{IN} = 3 V, I_O = -24 \text{ mA}$ 3.0	ParameterTest ConditionsVicc (V)MinTypHIGH Level Input Voltage1.65 - 1.95 2.3 - 5.5LOW Level Input Voltage0 $\leq V_{IN} \leq 5.5$ V0 - 5.5 ± 0.05 Input Leakage Current0 $\leq A, B \leq V_{CC}$ 1.65 - 5.5 ± 0.05 OFF State Leakage Current0 $\leq A, B \leq V_{CC}$ 1.65 - 5.5 ± 0.05 Switch On Resistance (Note 3) $V_{IN} = 0$ V, $I_0 = 30$ mA $V_{IN} = 2.4$ V, $I_0 = -30$ mA $V_{IN} = 4.5$ V, $I_0 = -30$ mA $V_{IN} = 3.4$ V, $I_0 = -30$ mA $V_{IN} = 3.5$ V, $I_0 = -30$ mA $V_{IN} = 3.5$ V, $I_0 = -30$ mA $V_{IN} = 3.4$ V, $I_0 = -30$ mA $V_{IN} = 2.3$ V, $I_0 = -4$ mA $V_{IN} = 1.65$ V, $I_0 = -4$ mA $V_{IN} = 1.65$ V, $I_0 = -4$ mA $V_{IN} = 1.65$ V, $I_0 = -4$ mA1.65Quiescent Supply Current All Channels ON or OFF $V_{IN} = 0$ V, $I_0 = 4$ mA $I_0UT = 0$ 5.5Quiescant Supply Current All Channels ON or OFF $I_A = -30$ mA, $0 \leq V_{Bn}$ $\leq V_{CC}$ $I_A = -4$ mA, $0 \leq V_{Bn}$ $\leq V_{CC}$ $I_A = -4$ mA, $0 \leq V_{Bn}$ $\leq V_{CC}$ 0On Resistance (Note 3) (Note 7) $I_A = -30$ mA, $V_{Bn} = 1.6$ $I_A = -30$ mA, $V_{Bn} = 1.6$ $I_A = -30$ mA, $0 \leq V_{Bn}$ $\leq V_{CC}$ $I_A = -4$ mA, $0 \leq V_{Bn}$ $\leq V_{CC}$ $I_A = -4$ mA, $V_{Bn} = 1.15$ $I_A = -4$ mA, $V_{Bn} = 1.15$ $I_A = -4$ mA, $V_{Bn} = 1.15$ $I_A = -4$ mA, $V_{Bn} = 1.5$ $I_A = -4$ mA, $0 \leq V_{Bn}$ 	Parameter Test Conditions Vecc (V) Min Typ Max HIGH Level Input Voltage	Parameter Test Conditions Wcc Min Typ Max Min HIGH Level Input Voltage 1.65-1.95 2.3-5.5 1 1 0.75 V _{CC} 0.7 V _{CC} LOW Level Input Voltage 0 $\leq V_{IN} \leq 5.5$ V 0-5.5 1 ± 0.05 ± 0.15 Input Leakage Current 0 $\leq V_{IN} \leq 5.5$ V 0-5.5 1 ± 0.05 ± 0.10 OFF State Leakage Current 0 $\leq A, B \leq V_{CC}$ 1.65-5.5 1 ± 0.05 ± 0.11 Switch On Resistance (Note 3) $V_{IN} = 0 V, I_0 = 30 \text{ mA}$ $V_{IN} = 2.4 V, I_0 = -30 \text{ mA}$ 3.0 5.0 5.0 5.0 $V_{IN} = 0, V, I_0 = 4 \text{ mA}$ $V_{IN} = 2.3 V, I_0 = -4 \text{ mA}$ 3.0 4.0 1.0 1.0 Quiescent Supply Current $V_{IN} = V_{CC}$ or GND $I_{UT} = 0$ 5.5 6.5 1.0 1.0 Quiescent Supply Current (All Channels ON or OFF $V_{IN} = V_{CC}$ or GND $I_{UT} = 0$ 4.5 5.0 4.5 5.0 1.0 1.0 Analog Signal Range (Note 3) (Note 7) $I_A = -30 \text{ mA}, 0 \leq V_{Bn}$ 2.3 2.3 0.5 0.5	ParameterTest ConditionsVCC MinMinTypMaxMinMaxHIGH Level Input Voltage

Measured by the voltage drop between A and B pins at the indicated current through the switch. On Resistance is determined by the lower of the voltages on the two (A or B Ports).
 Parameter is characterized but not tested in production.
 ΔR_{ON} = R_{ON} max - R_{ON} min measured at identical V_{CC}, temperature and voltage levels.
 Flatness is defined as the difference between the maximum and minimum value of On Resistance over the specified range of conditions.

7. Guaranteed by Design.

AC ELECTRICAL CHARACTERISTICS

			V _{CC}	T,	م = +25°	°C	T _A = -40°	C to +85°C		Figure
Symbol	Parameter	Test Conditions	(V)	Min	Тур	Max	Min	Max	Unit	Number
t _{PHL} t _{PLH}	Propagation Delay Bus to Bus (Note 9)	V _I = OPEN	1.65–1.95 2.3–2.7 3.0–3.6 4.5–5.5					1.2 0.8 0.3	ns	Figures 2, 3
t _{PZL} t _{PZH}	Output Enable Time Turn On Time (A to B _n)	$\label{eq:VI} \begin{array}{l} V_I = 2 \times V_{CC} \text{ for } t_{PZL} \\ V_I = 0 \; V \text{ for } t_{PZH} \end{array}$	1.65–1.95 2.3–2.7 3.0–3.6 4.5–5.5			23 13 6.9 5.2	7.0 3.5 2.5 1.7	24 14 7.6 5.7	ns	Figures 2, 3
t _{PLZ} t _{PHZ}	Output Disable Time Turn Off Time (A Port to B Port)	$\label{eq:VI} \begin{array}{l} V_I = 2 \times V_{CC} \text{ for } t_{PLZ} \\ V_I = 0 \; V \text{ for } t_{PHZ} \end{array}$	1.65–1.95 2.3–2.7 3.0–3.6 4.5–5.5			12.5 7.0 5.0 3.5	3.0 2.0 1.5 0.8	13 7.5 5.3 3.8	ns	Figures 2, 3
t _{B-M}	Break Before Make Time (Note 8)		1.65–1.95 2.3–2.7 3.0–3.6 4.5–5.5				0.5 0.5 0.5 0.5		ns	Figure 4
Q	Charge Injection (Note 8)	C_L = 0.1 nF, V_{GEN} = 0 V R _{GEN} = 0 Ω	5.0 3.3		7.0 3.0				рС	Figure 5
OIRR	Off Isolation (Note 10)	R _L = 50 Ω f = 10 MHz	1.65–5.5		-57				dB	Figure 6
Xtalk	Crosstalk	R _L = 50 Ω f = 10 MHz	1.65–5.5		-54				dB	Figure 7
BW	-3 dB Bandwidth	R _L = 50 Ω	1.65–5.5		250				MHz	Figure 10
THD	Total Harmonic Distortion (Note 8)	$R_{L} = 600 \Omega$ 0.5 V _{P-P} f = 600 Hz to 20 kHz	5.0		0.011				%	

CAPACITANCE (Note 11)

Symbol	Parameter	Test Conditions	Тур	Max	Unit	Figure Number
C _{IN}	Select Pin Input Capacitance	V _{CC} = 0 V	2.3		pF	
C _{IO-B}	B Port Off Capacitance	V _{CC} = 5.0 V	6.5		pF	Figure 8
C _{IOA-ON}	A Port Capacitance when Switch is Enabled	V _{CC} = 5.0 V	18.5		pF	Figure 9

8. Guaranteed by Design.
 9. This parameter is guaranteed by design but not tested. The bus switch contributes no propagation delay other than the RC delay of the On Resistance of the switch and the 50 pF load capacitance, when driven by an ideal voltage source (zero output impedance).
 10. Off Isolation = 20 log₁₀ [V_A/V_{Bn}].
 11. T_A = +25°C, f = 1 MHz, Capacitance is characterized but not tested in production.

APPENDIX A	
DC ELECTRICAL EXTENDED AUTOMOTIVE TEMPERATURE RANGE CHARACTERISTICS	

		Test Conditions	Vcc	٦	Γ _A = +25°0	2	T _A = -55°C		
Symbol	Parameter		(V)	Min	Тур	Max	Min	Max	Unit
V _{IH}	HIGH Level Input Voltage		1.65–1.95 2.3–5.5				0.75 V _{CC} 0.7 V _{CC}		V
V _{IL}	LOW Level Input Voltage		1.65–1.95 2.3–5.5					0.25 V _{CC} 0.3 V _{CC}	V
I _{IN}	Input Leakage Current	$0 \le V_{IN} \le 5.5 V$	0–5.5		±0.05	±0.1		±1	μA
I _{OFF}	OFF State Leakage Current	$0 \le A, B \le V_{CC}$	1.65–5.5		±0.05	±0.1		±1	μΑ
R _{ON}	Switch On Resistance (Note 12)		4.5		3.0 5.0 7.0			8.5 13.0 15.0	Ω
		$V_{IN} = 0 V$, $I_O = 24 mA$ $V_{IN} = 3 V$, $I_O = -24 mA$	3.0		4.0 10			11 20	
		$V_{IN} = 0 \text{ V}, I_O = 8 \text{ mA}$ $V_{IN} = 2.3 \text{ V}, I_O = -8 \text{ mA}$	2.3		5.0 13			12 30	
		$V_{IN} = 0 V$, $I_O = 4 mA$ $V_{IN} = 1.65 V$, $I_O = -4 mA$	1.65		6.5 17			20 50	
Icc	Quiescent Supply Current All Channels ON or OFF	$V_{IN} = V_{CC}$ or GND $I_{OUT} = 0$	5.5			1.0		10	μΑ
	Analog Signal Range		V _{CC}	0		V _{CC}	0	V _{CC}	V
R _{RANGE}	On Resistance Over Signal Range	$ \begin{array}{l} I_A = -30 \text{ mA}, 0 \leq V_{Bn} \leq V_{CC} \\ I_A = -24 \text{ mA}, 0 \leq V_{Bn} \leq V_{CC} \end{array} \end{array} $	4.5					25	Ω
	(Note 12) (Note 14)	$I_A = -8 \text{ mA}, 0 \le V_{Bn} \le V_{CC}$	3.0					50	
		$I_A = -4 \text{ mA}, 0 \le V_{Bn} \le V_{CC}$	2.3					100	
			1.65					300	

12. Measured by the voltage drop between A and B pins at the indicated current through the switch. On Resistance is determined by the lower of the voltages on the two (A or B Ports).

Flatness is defined as the difference between the maximum and minimum value of On Resistance over the specified range of conditions.
 Guaranteed by Design.

* For $\Delta R_{\text{ON}},\,R_{\text{FLAT}},\,Q,\,\text{OIRR},\,\text{Xtalk},\,\text{BW},\,\text{THD},\,\text{and}\,\,\text{CIN}\,\,\text{see}\,\,\text{-40}^\circ\text{C}$ to 85°C section.

APPENDIX A AC ELECTRICAL EXTENDED AUTOMOTIVE TEMPERATURE RANGE CHARACTERISTICS

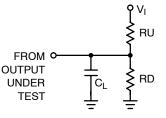
			V _{cc}	Tے	T _A = +25°C		T _A = -55°C to +125°C			Figure
Symbol	Parameter	Test Conditions	(V)	Min	Тур	Max	Min	Max	Unit	Number
t _{PHL} t _{PLH}	Propagation Delay Bus to Bus (Note 16)	V _I = OPEN	1.65–1.95 2.3–2.7 3.0–3.6 4.5–5.5					1.2 0.8 0.3	ns	Figures 2, 3
t _{PZL} t _{PZH}	Output Enable Time Turn On Time (A to B _n)	$\label{eq:VI} \begin{array}{l} V_{I} = 2 \ \times \ V_{CC} \ \text{for} \ t_{PZL} \\ V_{I} = 0 \ V \ \text{for} \ t_{PZH} \end{array}$	1.65–1.95 2.3–2.7 3.0–3.6 4.5–5.5			23 13 6.9 5.2	7.0 3.5 2.5 1.7	24 14 9.0 7.0	ns	Figures 2, 3
t _{PLZ} t _{PHZ}	Output Disable Time Turn Off Time (A Port to B Port)	$\label{eq:VI} \begin{array}{l} V_I = 2 \times V_{CC} \text{ for } t_{PLZ} \\ V_I = 0 V \text{ for } t_{PHZ} \end{array}$	1.65–1.95 2.3–2.7 3.0–3.6 4.5–5.5			12.5 7.0 5.0 3.5	3.0 2.0 1.5 0.8	13 7.5 6.5 5.0	ns	Figures 2, 3
t _{B-M}	Break Before Make Time (Note 15)		1.65–1.95 2.3–2.7 3.0–3.6 4.5–5.5				0.5 0.5 0.5 0.5		ns	Figure 4

15. Guaranteed by Design.
16. This parameter is guaranteed by design but not tested. The bus switch contributes no propagation delay other than the RC delay of the On Resistance of the switch and the 50 pF load capacitance, when driven by an ideal voltage source (zero output impedance).

* For ΔR_{ON} , R_{FLAT} , Q, OIRR, Xtalk, BW, THD, and CIN see –40°C to 85°C section.

AC LOADING AND WAVEFORMS

NOTE: Input driven by 50 Ω source terminated in 50 Ω NOTE: C_L includes load and stray capacitance NOTE: Input PRR = 1.0 MHz; t_W = 500 ns





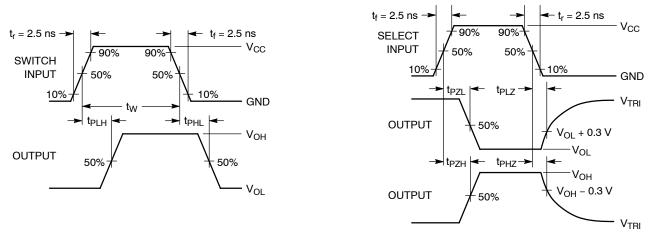
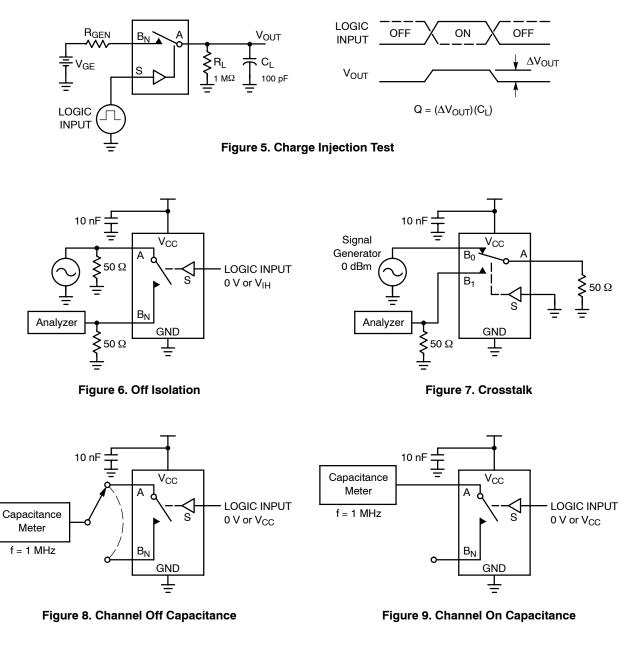


Figure 3. AC Waveforms



Figure 4. Break Before Make Interval Timing

AC LOADING AND WAVEFORMS



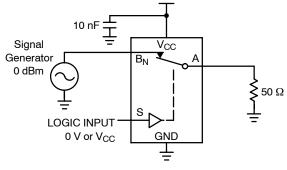
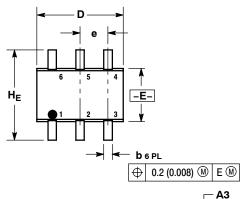
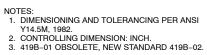


Figure 10. Bandwidth

PACKAGE DIMENSIONS

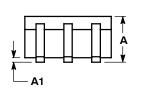
SC-88/SOT-363/SC-70 DF SUFFIX CASE 419B-02 **ISSUE W**

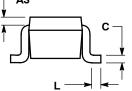




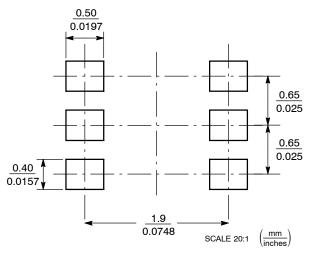
•	419B	-01	OBSOL	EIE,	NEW	STAN	DARD	419B	-0

	MIL	LIMETE	RS		INCHES	3
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.80	0.95	1.10	0.031	0.037	0.043
A1	0.00	0.05	0.10	0.000	0.002	0.004
A3		0.20 RE	F	(0.008 RI	EF
b	0.10	0.21	0.30	0.004	0.008	0.012
С	0.10	0.14	0.25	0.004	0.005	0.010
D	1.80	2.00	2.20	0.070	0.078	0.086
E	1.15	1.25	1.35	0.045	0.049	0.053
е		0.65 BS	С	0	.026 BS	С
L	0.10	0.20	0.30	0.004	0.008	0.012
HE	2.00	2.10	2.20	0.078	0.082	0.086





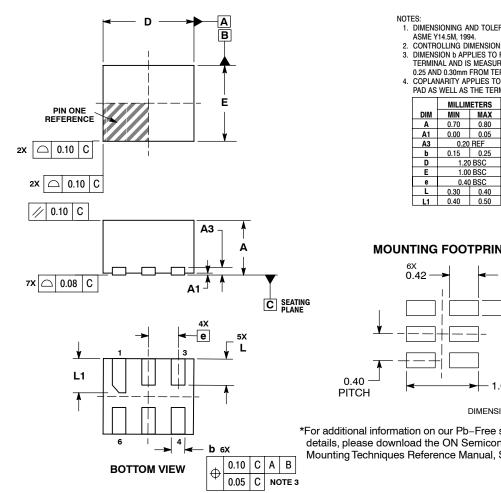
SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

WDFN6 1.2x1.0, 0.4P CASE 506AS-01 **ISSUE B**



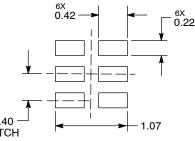
DIMENSIONING AND TOLERANCING PER

DIMENSIONING AND TOLERAINCING PER ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS. DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN

0.25 AND 0.30mm FROM TERMINAL. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

	MILLIMETERS	
DIM	MIN	MAX
Α	0.70	0.80
A1	0.00	0.05
A3	0.20 REF	
b	0.15	0.25
D	1.20 BSC	
E	1.00 BSC	
е	0.40 BSC	
L	0.30	0.40
11	0.40	0.50

MOUNTING FOOTPRINT*



DIMENSIONS: MILLIMETERS

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